4V Drive Pch MOSFET

RSM002P03

●Structure

Silicon P-channel MOSFET

●Features

- 1) Low On-resistance.
- 2) Small package (VMT3).
- 3) 4V drive.

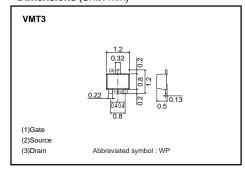
Applications

Switching

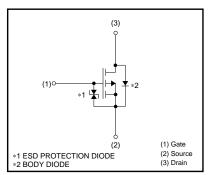
●Packaging specifications

	Package	Taping	
Type	Code	T2L	
	Basic ordering unit (pieces)	8000	
RSM002P03	0		

● Dimensions (Unit: mm)



●Inner circuit



● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit			
Drain-source voltage		V _{DSS}	-30	V			
Gate-source voltage		V _{GSS}	±20	V			
Drain current	Continuous	lσ	±0.2	Α			
	Pulsed	I _{DP} *1	±0.4	Α			
Total power dissipation	P _D *2	0.15	W				
Channel temperature		Tch	150	°C			
Range of storage temperature		Tstg	-55 to +150	°C			

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	Rth(ch-a)*	833	°C/W

^{*} Each terminal mounted on a recommended land

^{*1} Pw≤10μs, Duty cycle≤1% *2 Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	-	-	±10	μΑ	V _{GS} = ±20V, V _{DS} =0V
Drain-source breakdown voltage	$V_{(BR)\;DSS}$	-30	-	_	V	I _D = -1mA, V _G S=0V
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	V _{DS} = -30V, V _{GS} =0V
Gate threshold voltage	VGS (th)	-1.0	-	-2.5	٧	Vps= -10V, Ip= -1mA
Static drain-source on-state resistance	R _{DS (on)} *	-	0.9	1.4	Ω	I _D = -0.2A, V _G S= -10V
		-	1.4	2.1	Ω	I _D = -0.15A, V _G s= -4.5V
		-	1.6	2.4	Ω	ID= -0.15A, VGS= -4.0V
Forward transfer admittance	Y _{fs} *	0.2	-	_	S	V _{DS} = -10V, I _D = -0.15A
Input capacitance	Ciss	-	30	_	pF	V _{DS} = -10V
Output capacitance	Coss	_	4	_	pF	V _{GS} = 0V
Reverse transfer capacitance	Crss	-	5	_	pF	f=1MHz
Turn-on delay time	t _{d (on)} *	-	8	_	ns	Vpp≒ –15V
Rise time	tr *	-	5	-	ns	ID= -0.15A
Turn-off delay time	t _{d (off)} *	-	30	-	ns	V _{GS} = -10V R _L = 100Ω
Fall time	t _f *	_	40	-	ns	R _G = 10Ω

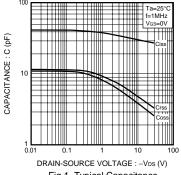
^{*}Pulsed

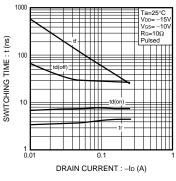
●Body diode characteristics (Source-drain) (Ta=25°C)

		,	`	,		
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp	_	_	-1.2	V	I _S = -0.1A, V _{GS} =0V

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Electrical characteristics curves





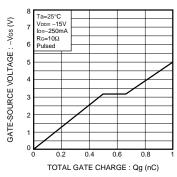
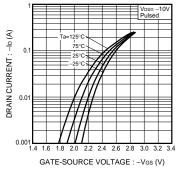
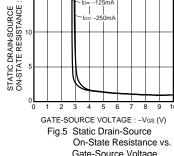


Fig.1 Typical Capacitance vs. Drain-Source Voltage

Fig.2 Switching Characteristics

Fig.3 Dynamic Input Characteristics





G R_{DS}

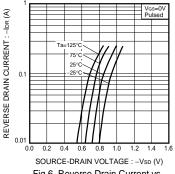
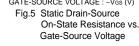
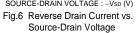


Fig.4 Typical Transfer Characteristics





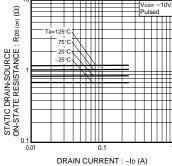


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (I)

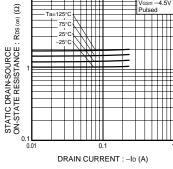


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current (II)

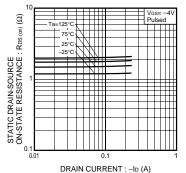


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current (III)

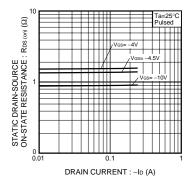


Fig.10 Static Drain-Source On-State Resistance vs. Drain Current (IV)

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